

Applications

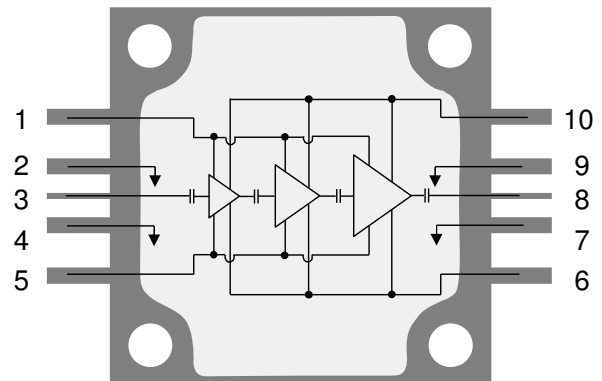
- Commercial VSAT
- Military Satcom
- Datalinks
- Radar



Product Features

- Frequency Range: 13.4 – 16.5 GHz
- Pout: 44 dBm @ PIN = 16 dBm
- PAE: > 31% @ PIN = 16 dBm
- Large Signal Gain: 28 dB @ PIN = 16 dBm
- Small Signal Gain: > 30 dB
- Bias: $V_D = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $V_G = -2.7\text{ V}$ Typical
- Package base is pure Cu offering superior thermal management
- Process Technology: TQGaN15
- Package Dimensions: 15.2 x 15.2 x 3.5 mm

Functional Block Diagram



General Description

TriQuint's TGA2219-CP is a 3-stage, 25 W power amplifier operating over the 13.4 to 16.5 GHz band. Fabricated on TriQuint's production 0.15um GaN on SiC technology, this high performance amplifier offers > 30dB small-signal gain with 31% PAE, allowing the system designer to achieve superior performance levels in a cost efficient manner.

The TGA2219-CP is offered in a 10-lead 15 x 15 mm bolt-down package. Assembled with a pure-copper base, coupled with its high efficiency, the TGA2219-CP minimizes the strain on the system-level cooling requirements, further reducing system operating costs. Superior electrical performance and thermal management makes the TGA2219-CP ideal for supporting communications and radar applications in both commercial and military markets.

Both RF ports have integrated DC blocking capacitors and are fully matched to 50 Ohms.

Lead free and RoHS compliant.

Evaluation Boards are available upon request.

Pin Configuration

Pad No.	Symbol
1, 5	V_G
2, 4, 7, 9	GND
3	RF _{IN}
6, 10	V_D
8	RF _{OUT}

Ordering Information

Part	ECCN	Description
TGA2219-CP	3A001.b.2.c	13.4 – 16.5 GHz, 25 W GaN Power Amplifier

Absolute Maximum Ratings

Parameter	Value
Drain Voltage (V_D)	29.5 V
Gate Voltage Range (V_G)	-8 to 0 V
Drain Current (I_D)	7.2 A
Gate Current (I_G)	See plot on page 3
Power Dissipation (P_{DISS}), 85 °C	80 W
Input Power (P_{IN}), CW, 50Ω, $V_D = 28$ V, $I_{DQ} = 450$ mA, 85 °C	30 dBm
Input Power (P_{IN}), CW, VSWR 3:1, $V_D = 28$ V, $I_{DQ} = 450$ mA, 85 °C	27 dBm
Channel Temperature (T_{CH})	275 °C
Mounting Temperature (30 Seconds)	260 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Value
Drain Voltage (V_D)	28 V
Drain Current (I_{DQ})	450 mA
Gate Voltage (V_G)	-2.7 V (Typ.)

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: 25 °C, $V_D = 28$ V, $I_{DQ} = 450$ mA, $V_G = -2.7$ V Typ, CW.

Parameter	Min	Typical	Max	Units
Operational Frequency Range	13.4		16.5	GHz
Small Signal Gain		> 30		dB
Input Return Loss		> 15		dB
Output Return Loss		> 5		dB
Output Power @ $P_{in} = 16$ dBm		44		dBm
Power Added Efficiency @ $P_{in} = 16$ dBm		> 31		%
Small Signal Gain Temperature Coefficient		-0.08		dB/°C
Output Power Temperature Coefficient (Temp: -40 °C – 85 °C @ $P_{in} = 16$ dBm)		-0.011		dBm/°C
Recommended Operating Voltage		20 to 28	28	V

Thermal and Reliability Information

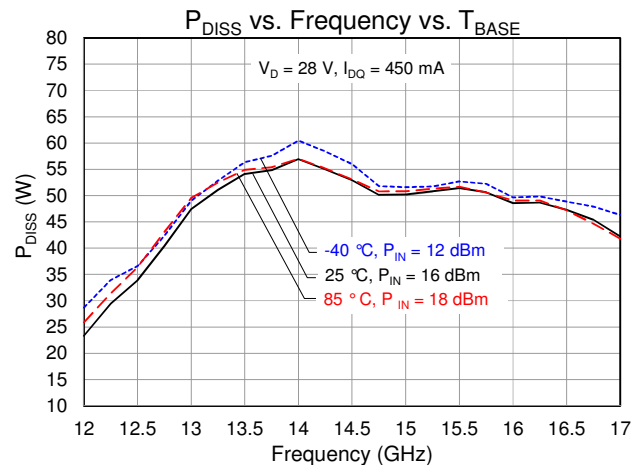
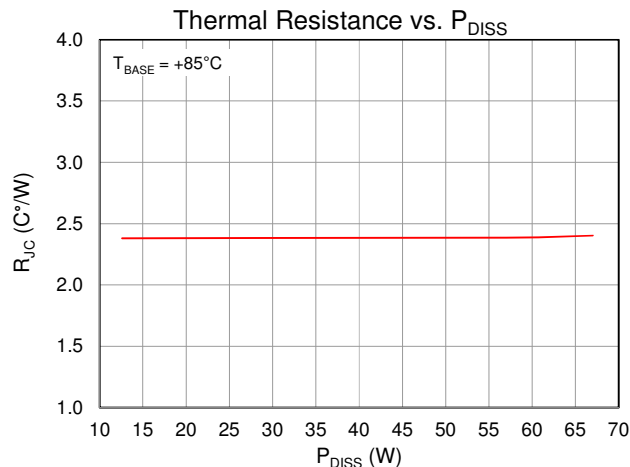
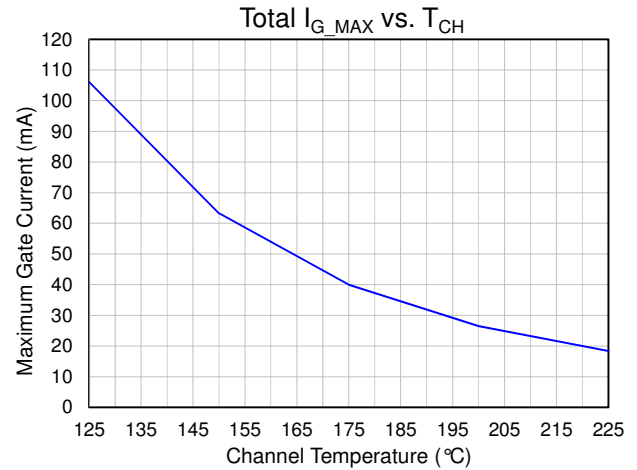
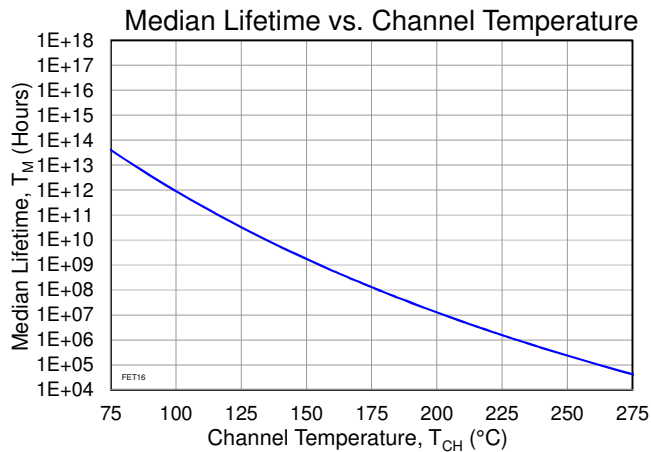
Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) ⁽¹⁾		2.38	$^{\circ}\text{C}/\text{W}$
Channel Temperature (T_{CH}) (Quiescent)	$T_{BASE} = 85^{\circ}\text{C}$, $V_D = 28\text{ V}$ (CW) At $I_{DQ} = 450\text{ mA}$, $P_{DISS} = 12.8\text{ W}$	115	$^{\circ}\text{C}$
Median Lifetime (T_M)		5.58E+11	Hrs
Thermal Resistance (θ_{JC}) ⁽¹⁾	$T_{BASE} = 85^{\circ}\text{C}$, $V_D = 28\text{ V}$ (CW)	2.39	$^{\circ}\text{C}/\text{W}$
Channel Temperature (T_{CH}) (Under RF drive)	At Freq = 14 GHz, $P_{IN} = 18\text{ dBm}$: $I_{DQ} = 450\text{ mA}$, $I_{D_Drive} = 2.9\text{ A}$	221	$^{\circ}\text{C}$
Median Lifetime (T_M)	$P_{OUT} = 44\text{ dBm}$, $P_{DISS} = 57\text{ W}$	1.02E+7	Hrs

Notes:

1. Thermal resistance measured to back of package.

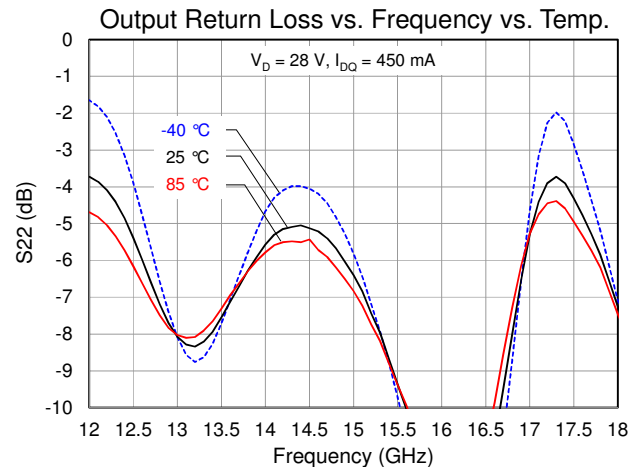
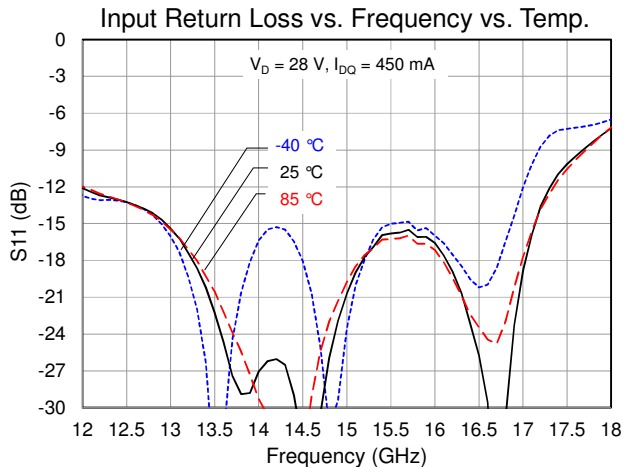
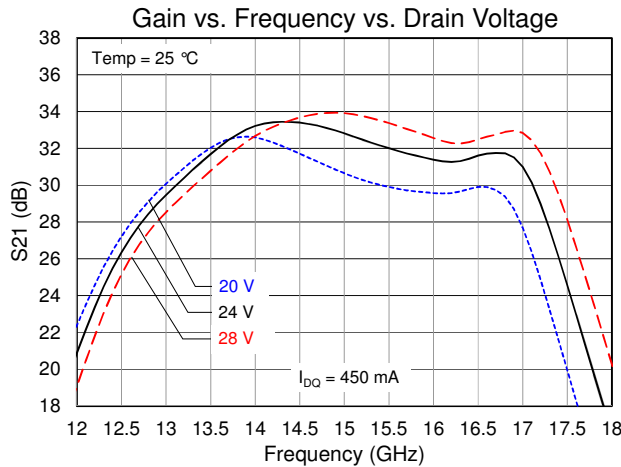
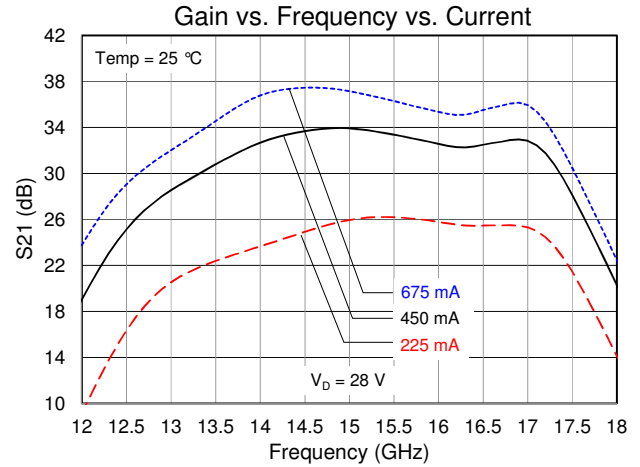
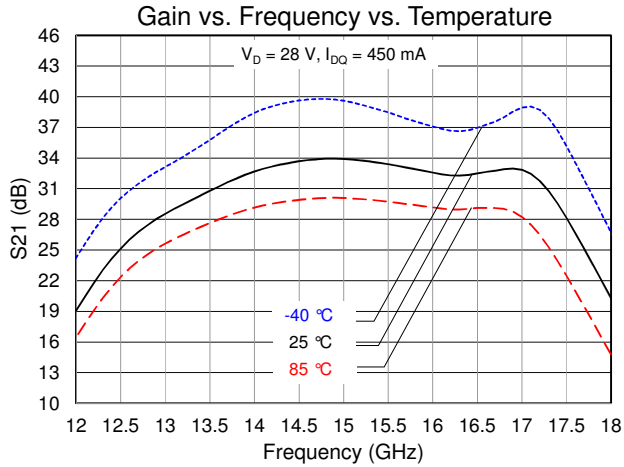
Median Lifetime

Test Conditions: $V_D = 28\text{ V}$; Failure Criteria = 10% reduction in I_{D_MAX}



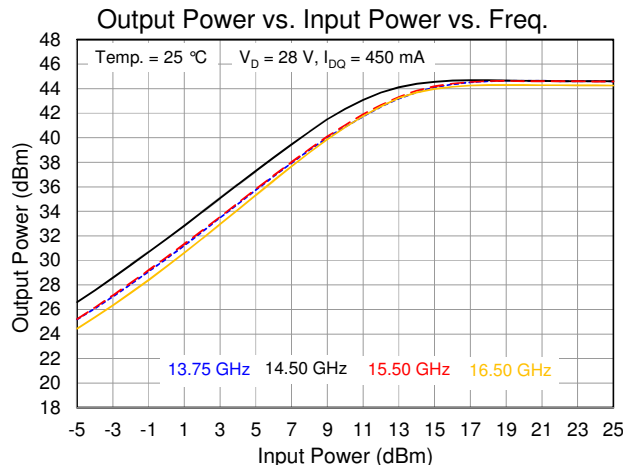
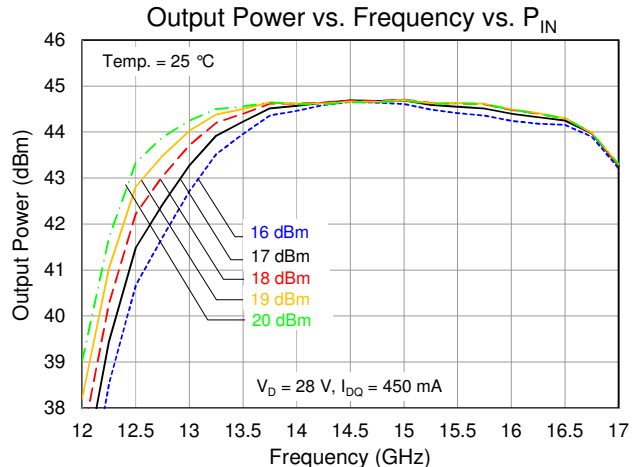
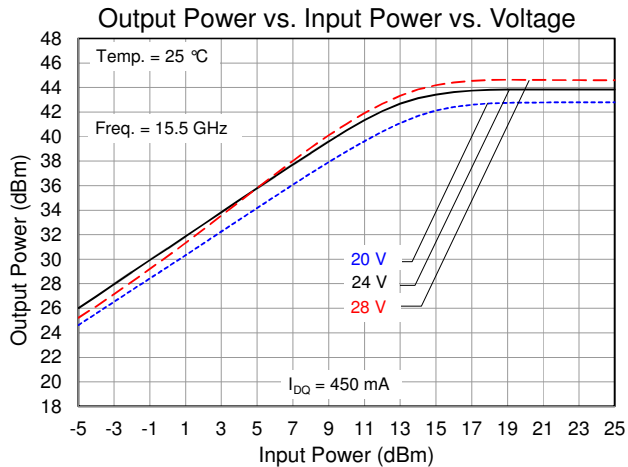
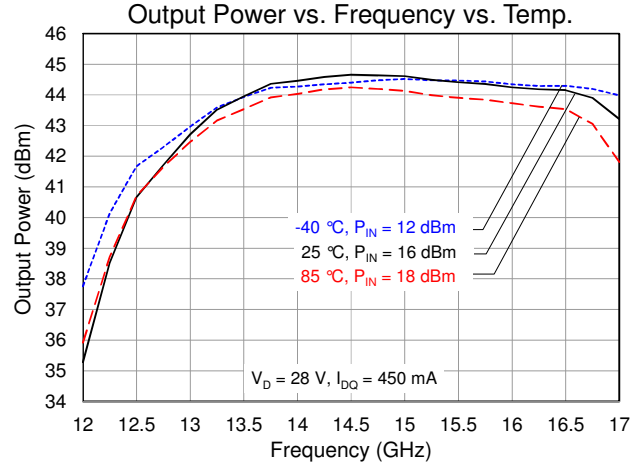
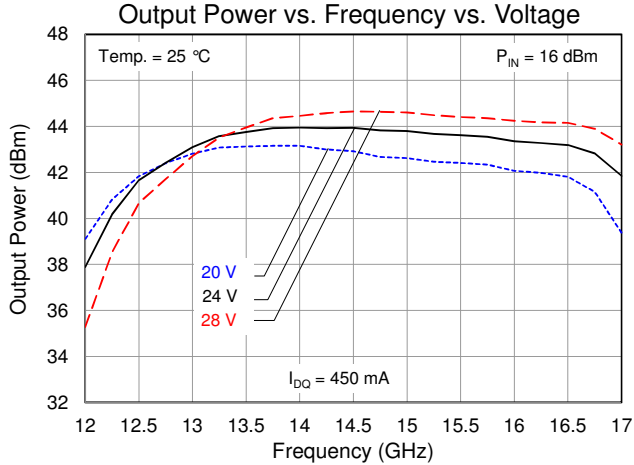
Typical Performance: Small Signal

Conditions unless otherwise specified: $V_D = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $V_G = -2.7\text{ V}$ Typical, CW.



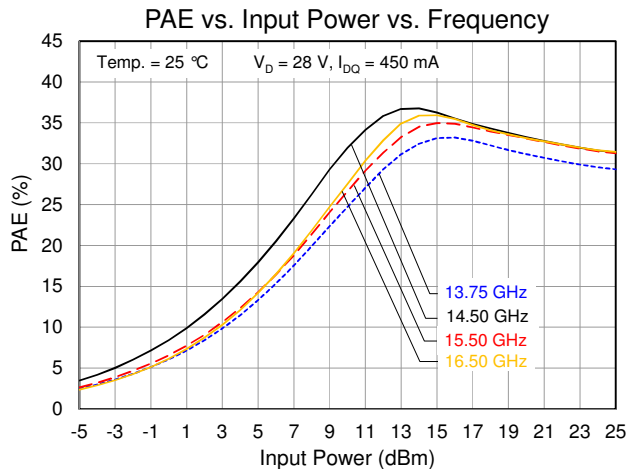
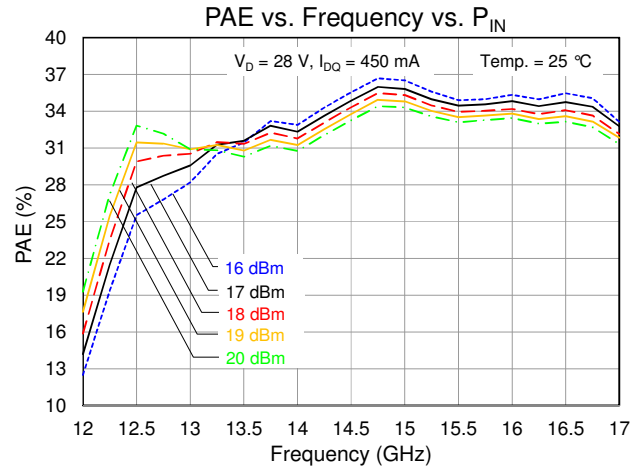
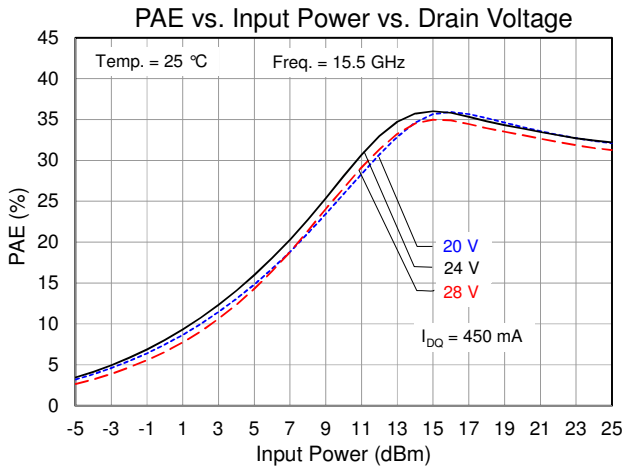
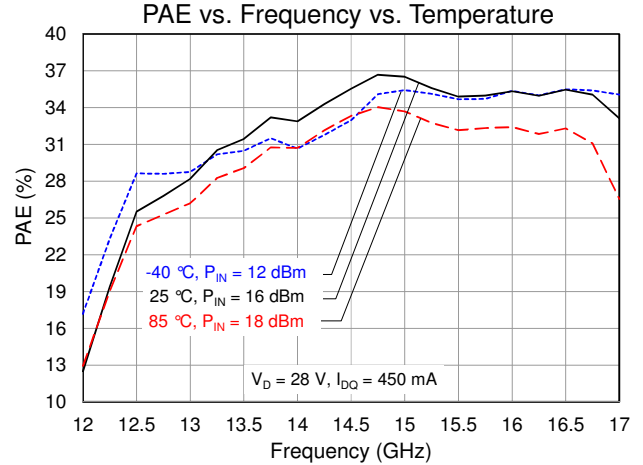
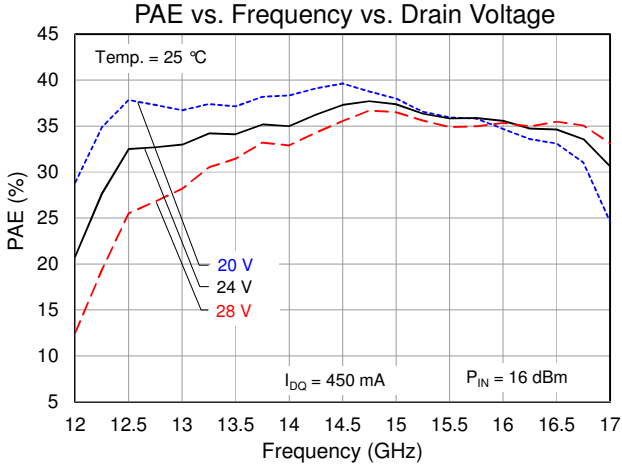
Typical Performance: Large Signal

Conditions unless otherwise specified: $V_D = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, -2.7 V Typical, CW.



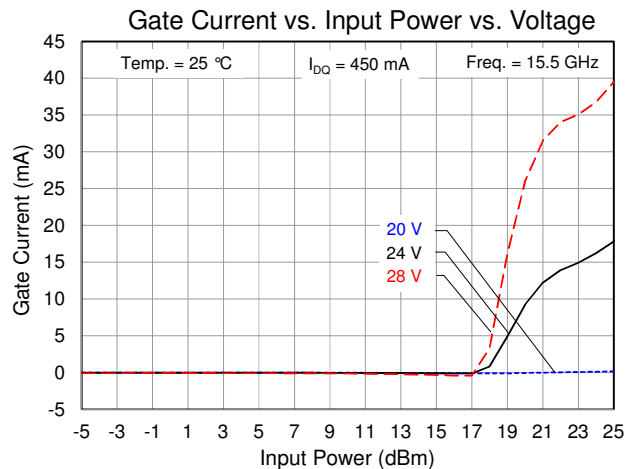
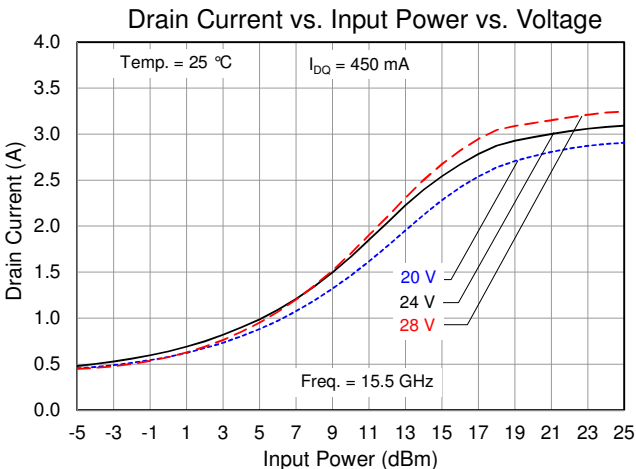
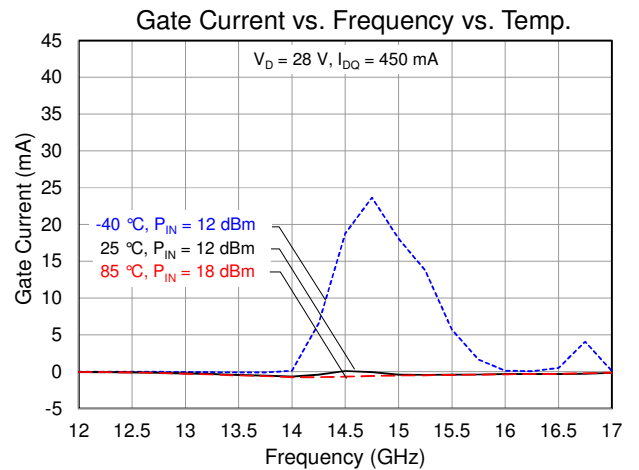
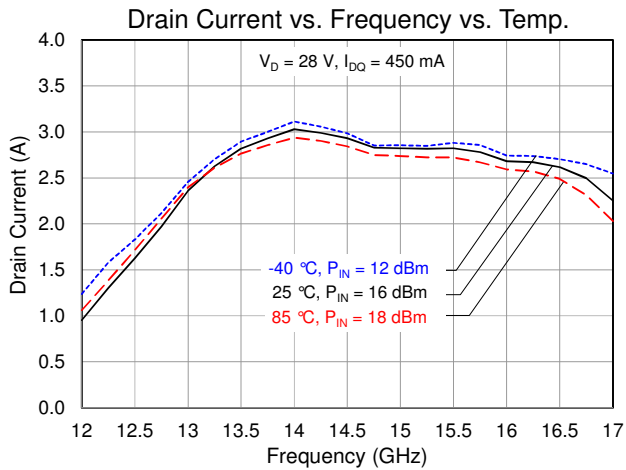
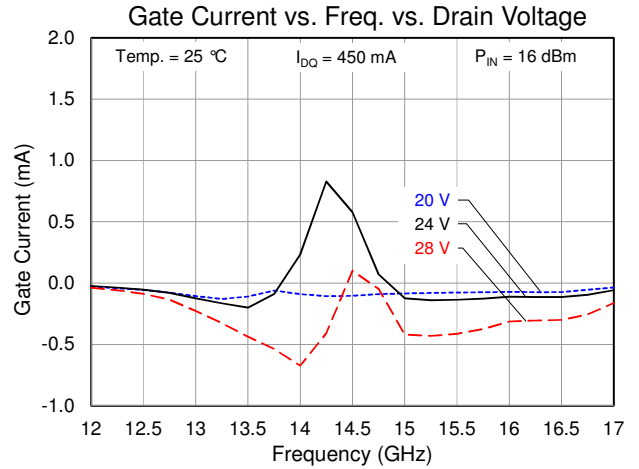
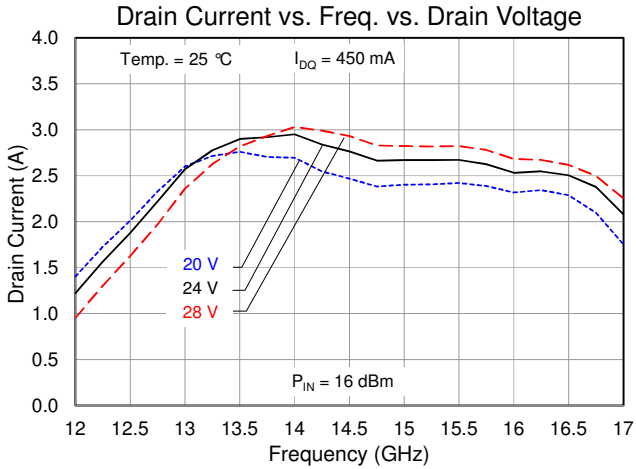
Typical Performance: Large Signal

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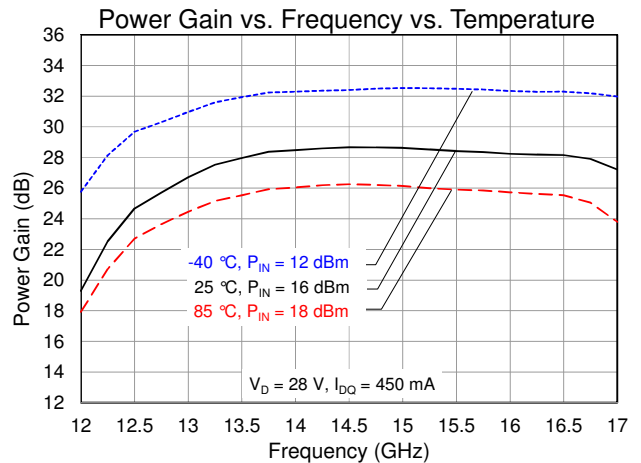
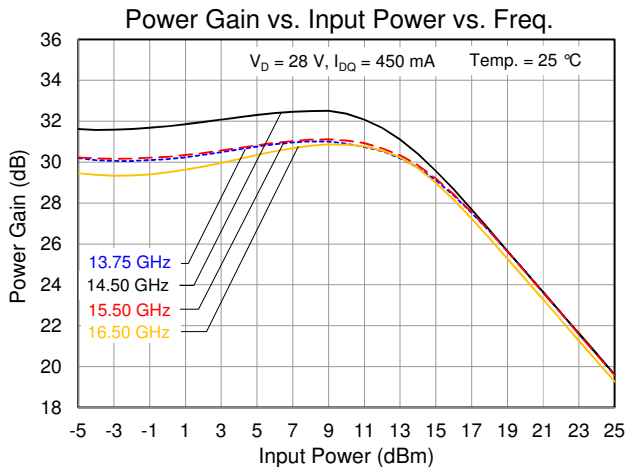
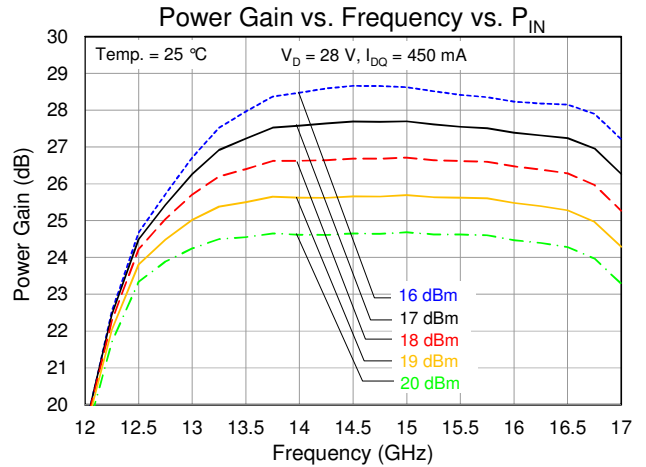
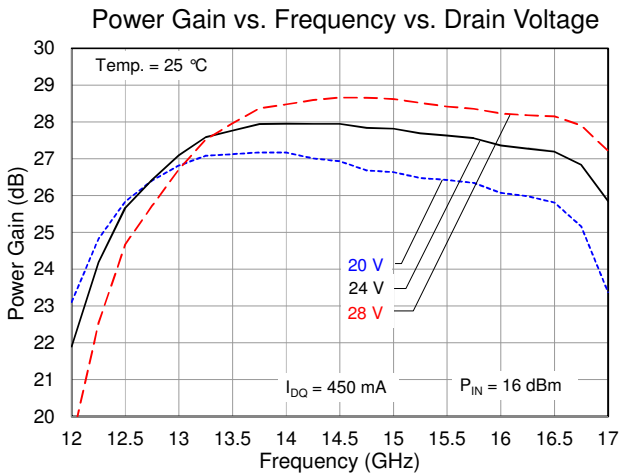
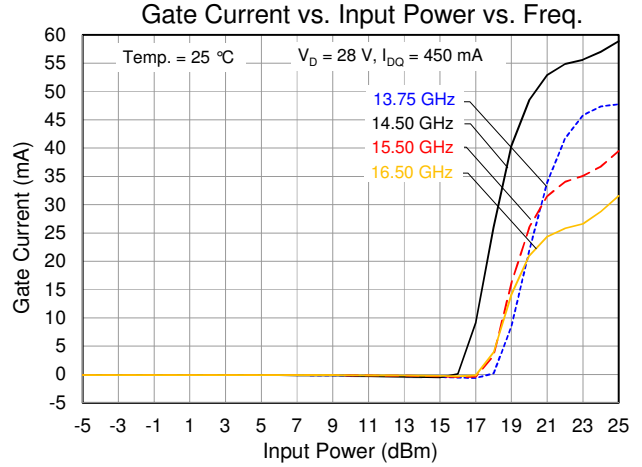
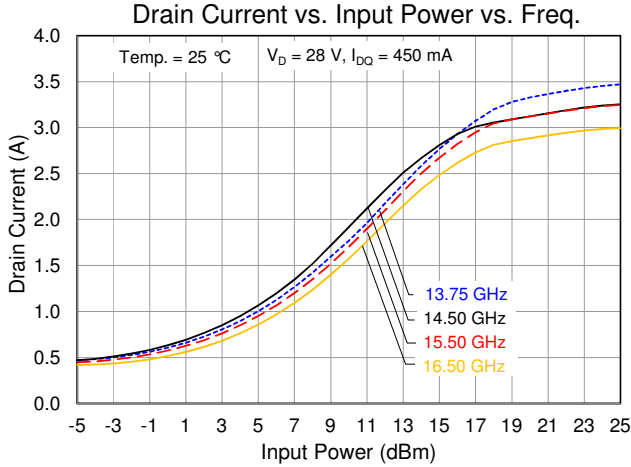
Typical Performance: Large Signal

Conditions unless otherwise specified: $V_D = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $V_G = -2.7\text{ V}$ Typical, CW.



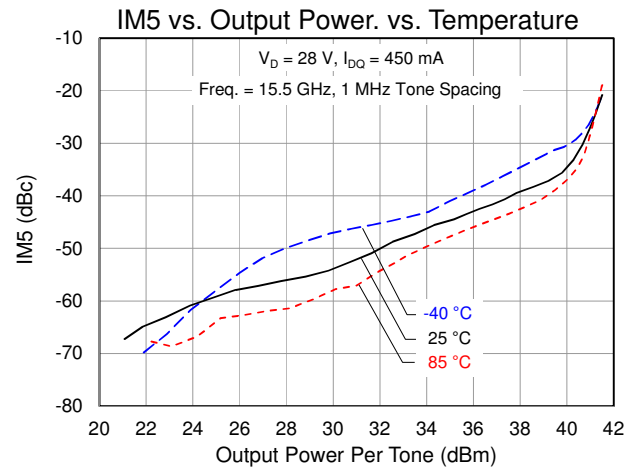
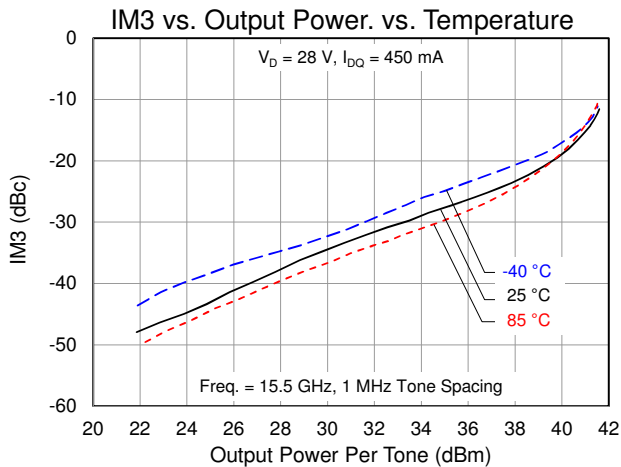
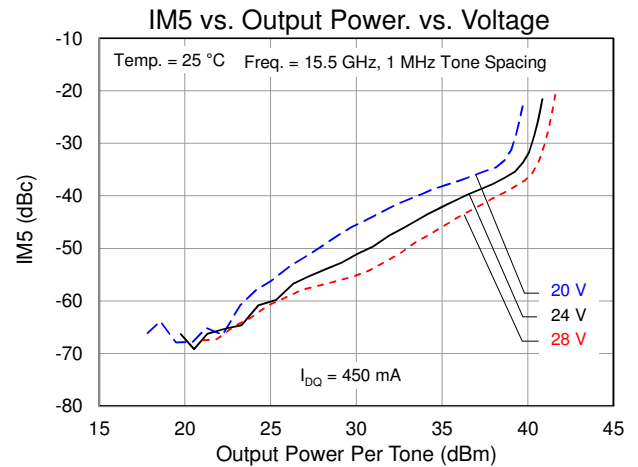
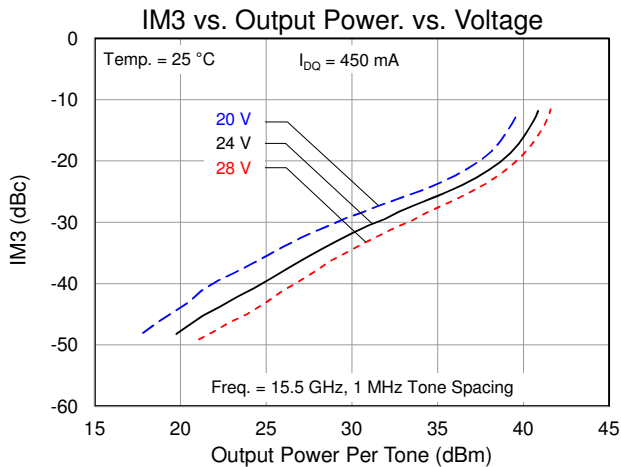
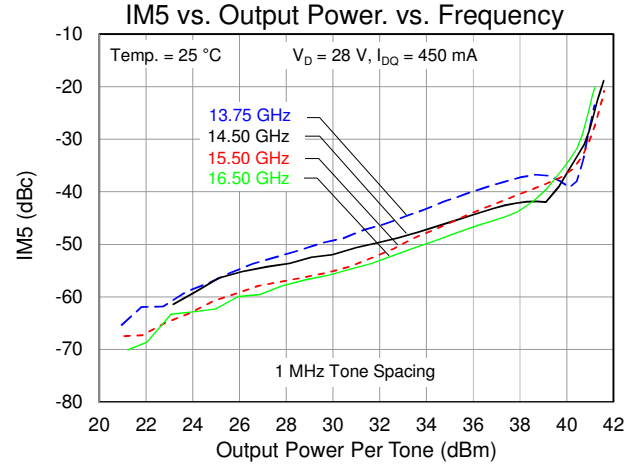
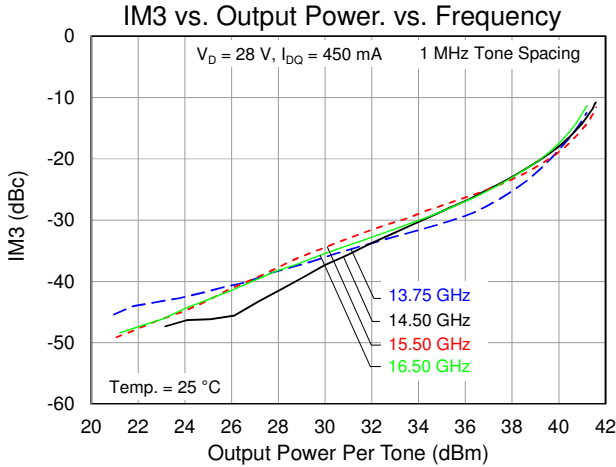
Typical Performance: Large Signal

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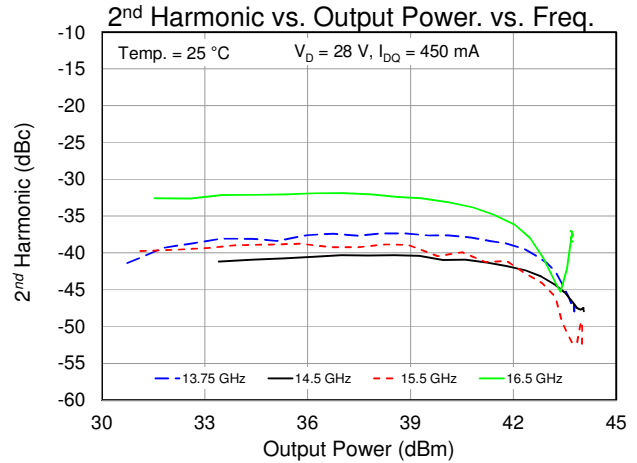
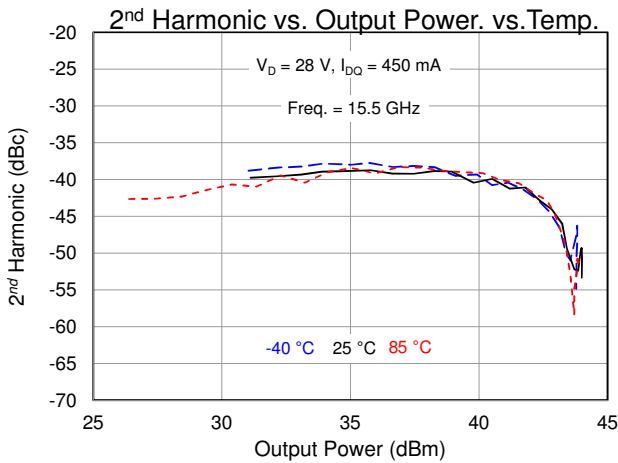
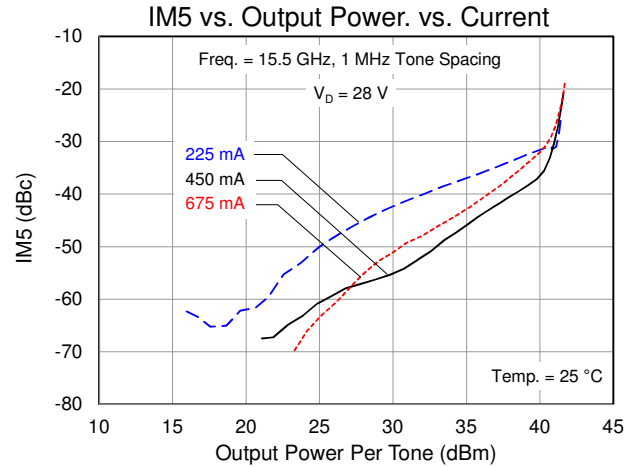
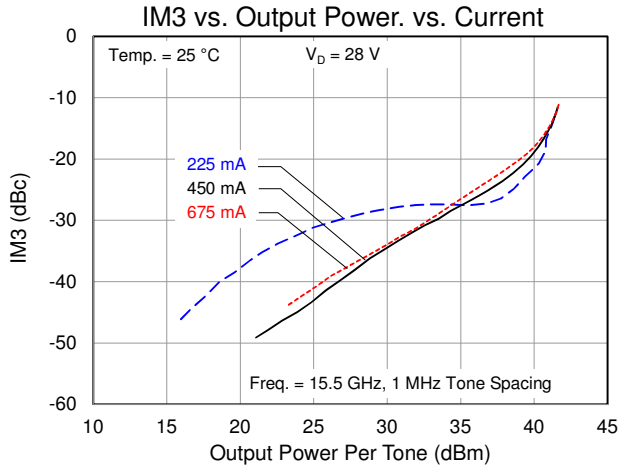
Typical Performance: Linearity

Conditions unless otherwise specified: $V_D = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $V_G = -2.7\text{ V}$ Typical, CW.

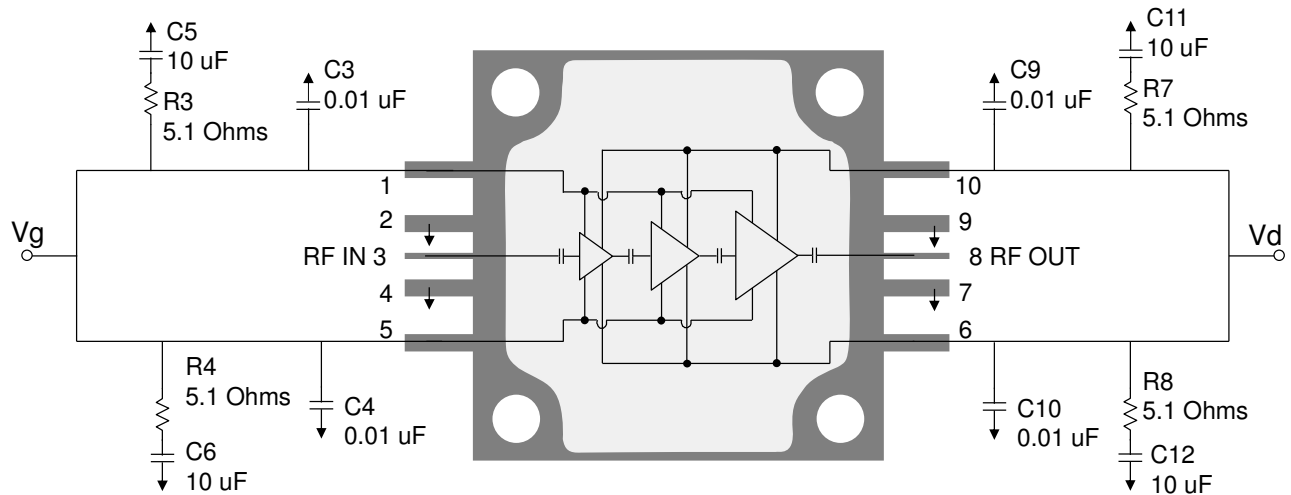


Typical Performance: Large Signal

Conditions unless otherwise specified: $V_D = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $V_G = -2.7\text{ V}$ Typical, CW.



Applications Information and Pin Layout



Notes: V_G and V_D can be biased from either side of top or bottom.

Bias-up Procedure

1. Set I_D limit to 3.5 A, I_G limit to 65 mA
2. Apply -5 V to V_G
3. Apply $+28$ V to V_D ; ensure I_{DQ} is approx. 0 mA
4. Adjust V_G until $I_{DQ} = 450$ mA ($V_G \sim -2.7$ V Typ.).
5. Turn on RF supply

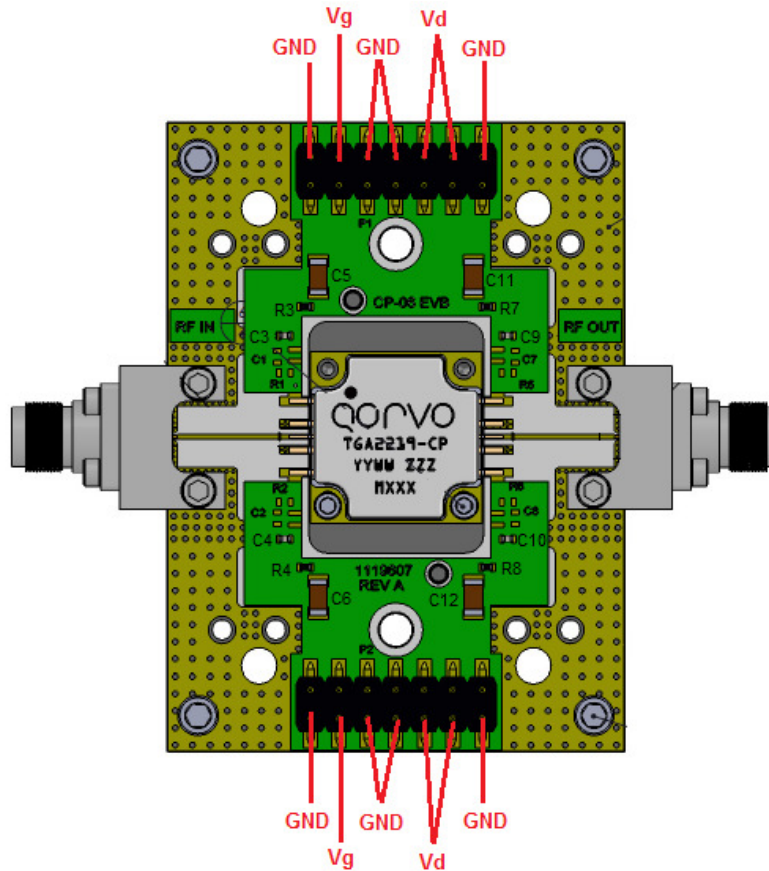
Bias-down Procedure

1. Turn off RF supply
2. Reduce V_G to -5 V; ensure I_{DQ} is approx. 0 mA
3. Set V_D to 0 V
4. Turn off V_D supply
5. Turn off V_G supply

Pin Description

Pin No.	Symbol	Description
1,5	V_G	Gate Voltage; Bias network is required; see recommended Application Information above.
3	RF_{IN}	Input; matched to 50Ω ; DC blocked
2,4,7,9	GND	Must be grounded on the PCB.
6,10	V_D	Drain voltage; Bias network is required; see recommended Application Information above.
8	RF_{OUT}	Output; matched to 50Ω ; DC blocked

Evaluation Board



NOTE: V_G and V_D can be biased from either side of top or bottom.

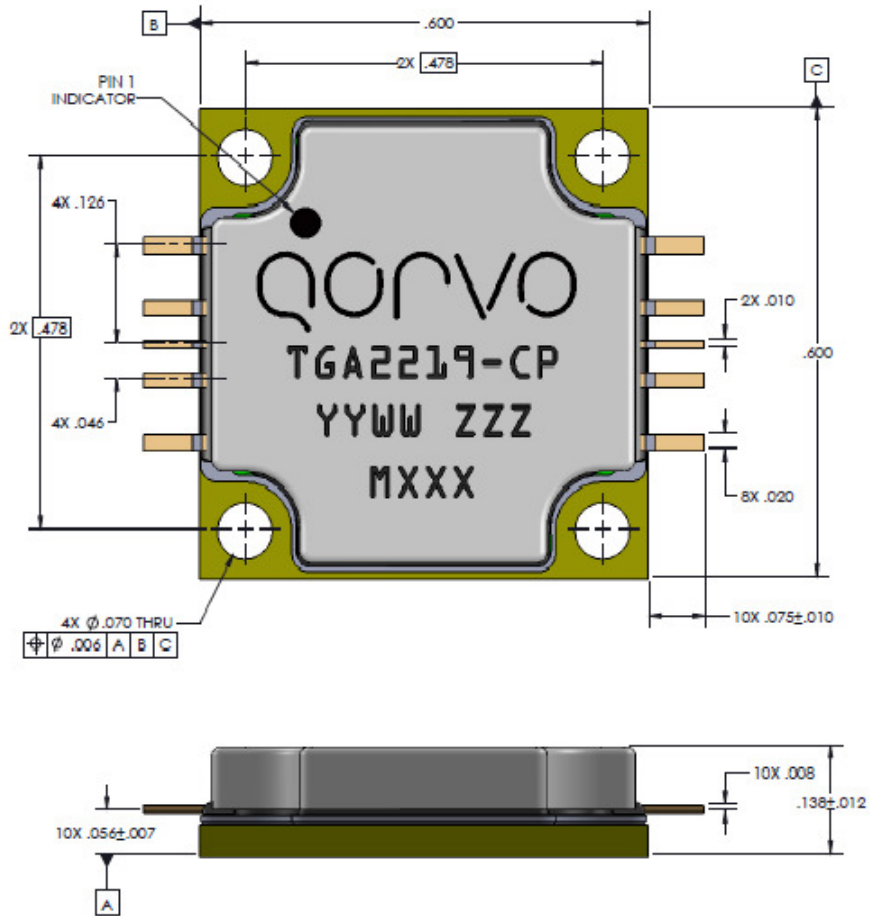
Bill of Material

Reference Des.	Value	Description	Manuf.	Part Number
C3, C4, C9, C10	0.01 μ F	Cap, 0402, 50 V, 10%, X7R	Various	
C5, C6, C11, C12	10 μ F	Cap, 1206, 50 V, 20%, X5R	Various	
R3, R4, R7, R8	5.1 Ohm	Res, 0402, 50V, 5%	Various	

Assembly Notes

1. Clean the board or module with alcohol. Allow it to dry fully.
2. Nylock screws are recommended for mounting the TGA2219-CP to the board.
3. To improve the thermal and RF performance, we recommend the following:
 - a. Apply a small amount thermal compound (Arctic Silver) or 4 mils indium shim between the package and the board.
 - b. Attach a heat sink to the bottom of the board and apply thermal grease or 4 mils indium shim between the heat sink and the board.
4. Apply solder to each pin of the TGA2219-CP.
5. Clean the assembly with alcohol.

Mechanical Information



Units: inches

Tolerances: unless specified

x.xx = ± 0.01

x.xxx = ± 0.005

Materials:

Base: Copper

Lid: LCD (Liquid Crystal Polymer)

All metalized features are gold plated

Part is epoxy sealed

Marking:

2219-CP: Part number

YY: Part Assembly year

WW: Part Assembly week

ZZZ: Serial Number

MXXX: Batch ID

Product Compliance Information

ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: Class 0B
Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

ESD Rating: Class C0B
Test: Charge Device Body Model (CDM)
Standard: JEDEC Standard JESD22-C101F

MSL Rating

Level 5A at 260 °C convection reflow.
The part is rated Moisture Sensitivity Level 5A at 260 °C per JEDEC standard IPC/JEDEC J-STD-020.

ECCN

US Department of Commerce: 3A001.b.2.c

Solderability

Compatible with the latest version of J-STD-020, Lead-free solder, 260°C

RoHS Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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Important Notice

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TriQuint products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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